

# ESD103-B1-02ELS

Bi-directional ESD protection device, 15 V, 0.09 pF, 0201



## Product description

ESD protection device with a bi-directional symmetric I/V characteristic and excellent clamping performance, extremely low capacitance and high linearity for mobile device antenna.

## Feature list

- ESD/transient protection according to:
  - IEC61000-4-2 (ESD):  $\pm 14$  kV (air) /  $\pm 10$  kV (contact)
- Bi-directional maximum working voltage:  $V_{WM} = \pm 15$  V
- Line capacitance:  $C_L = 0.09$  pF at  $f = 1$  GHz
- Clamping voltage:  $V_{cl} = 48$  V at  $I_{TLP} = 16$  A with  $R_{dyn} = 1.8 \Omega$
- Very low leakage current:  $I_L = 0.1$  nA
- Small form factor SMD size, low profile (0.62 x 0.32 x 0.31 mm<sup>3</sup>)



## Potential applications

- RF antennas and interfaces (LTE, WLAN)

## Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

## Device information

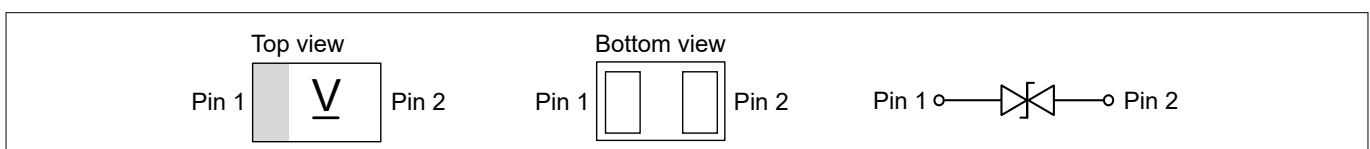


Figure 1 Pin configuration and schematic diagram

Table 1 Part information

Product name / Ordering code	Package	Pin configuration	Marking	Pieces / Reel
ESD103-B1-02ELS/ESD103B102ELSE6327XTSA1	TSSLP-2-4	1 line, bi-directional	<u>V</u>	15 k

**Table of contents**

	<b>Product description</b> .....	1
	<b>Feature list</b> .....	1
	<b>Potential applications</b> .....	1
	<b>Product validation</b> .....	1
	<b>Device information</b> .....	1
	<b>Table of contents</b> .....	2
<b>1</b>	<b>Absolute maximum ratings</b> .....	3
<b>2</b>	<b>Electrical characteristics</b> .....	4
<b>3</b>	<b>Typical characteristic diagrams</b> .....	6
<b>4</b>	<b>Package information TSSLP-2-4</b> .....	10
<b>5</b>	<b>References</b> .....	11
<b>6</b>	<b>Revision history</b> .....	11
	<b>Disclaimer</b> .....	12

## 1 Absolute maximum ratings

### 1 Absolute maximum ratings

**Table 2** Absolute maximum ratings at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Values		Unit	Note or test condition
		Min.	Max.		
Working voltage	$V_{WM}$	-15	+15	V	
ESD discharge voltage	$V_{ESD}$ (contact)	-10	+10	kV	Discharge network: $R = 330 \Omega$ , $C = 150 \text{ pF}$ <sup>1)</sup>
	$V_{ESD}$ (air)	-14	+14		
Operating temperature	$T_{op}$	-55	+125	°C	
Storage temperature	$T_{stg}$	-65	+150		

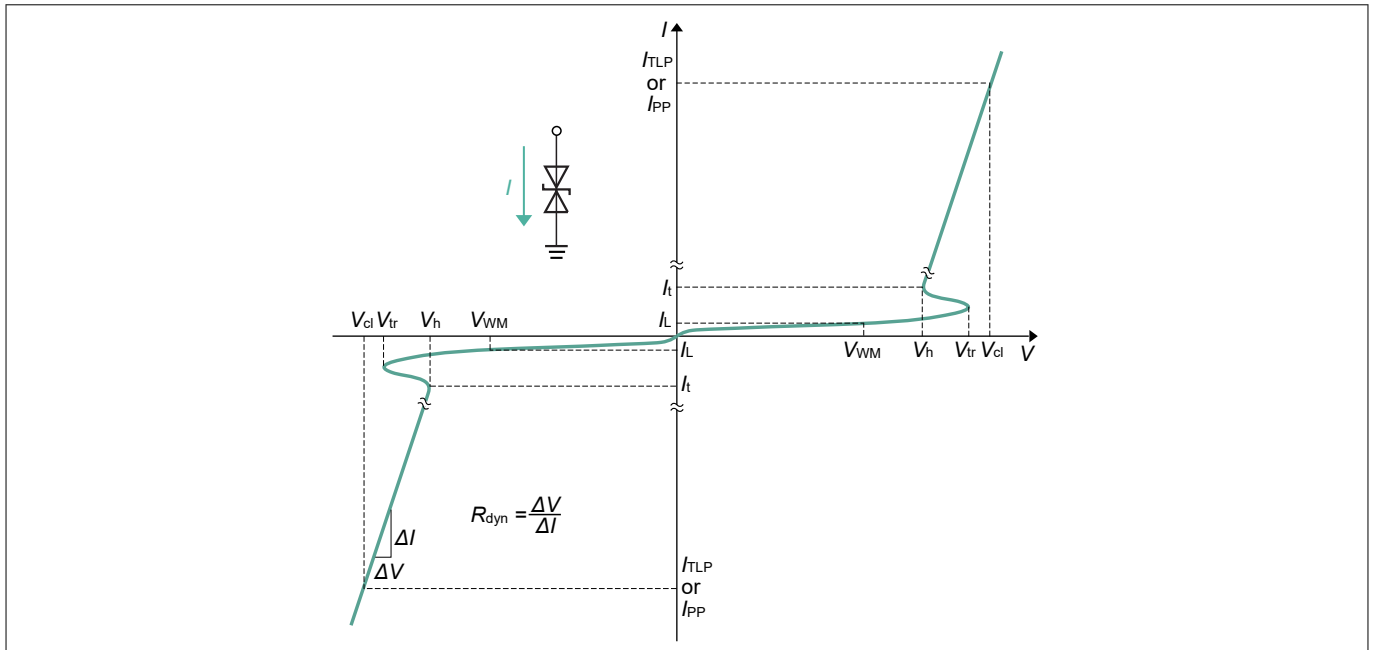
**Attention:** *Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.*

<sup>1</sup> Based on IEC61000-4-2.

**2 Electrical characteristics**

**2 Electrical characteristics**

Note:  $T_A = 25^\circ\text{C}$ , unless otherwise specified. Device is electrically symmetrical.



**Figure 2** **I/V characteristic curve**

**Table 3** **I/V characteristic parameters**

Symbol	Parameter
$I_h$	Holding current
$I_L$	Leakage current
$I_{PP}$	Peak pulse current, based on IEC61000-4-5
$I_t$	Test current
$I_{TLP}$	TLP current
$R_{dyn}$	Dynamic resistance
$V_{cl}$	Clamping voltage
$V_h$	Holding voltage
$V_t$	Test voltage
$V_{tr}$	Trigger voltage
$V_{WM}$	Maximum working voltage

## 2 Electrical characteristics

**Table 4 DC characteristics**

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Trigger voltage <sup>2)</sup>	$V_{tr}$	-	21	-	V	
leakage current	$I_L$	-	0.1	50	nA	$V_{WM} = 15\text{ V}$

**Table 5 AC characteristics**

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Line capacitance	$C_L$	-	0.13	0.2	pF	$V = 0\text{ V}, f = 1\text{ MHz}$
		-	0.09	-		$V = 0\text{ V}, f = 1\text{ GHz}$
Series inductance	$L_S$	-	0.2	-	nH	Extracted from S-parameters

**Table 6 Protection characteristics**

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Clamping voltage (TLP) <sup>3) 4)</sup>	$V_{cl}$	-	20	-	V	$I_{TLP} = 1\text{ A}$
		-	36	-		$I_{TLP} = 8\text{ A}$
		-	48	-		$I_{TLP} = 16\text{ A}$
Dynamic resistance <sup>3)</sup>	$R_{dyn}$	-	1.8	-	$\Omega$	

<sup>2)</sup> Verified by design.

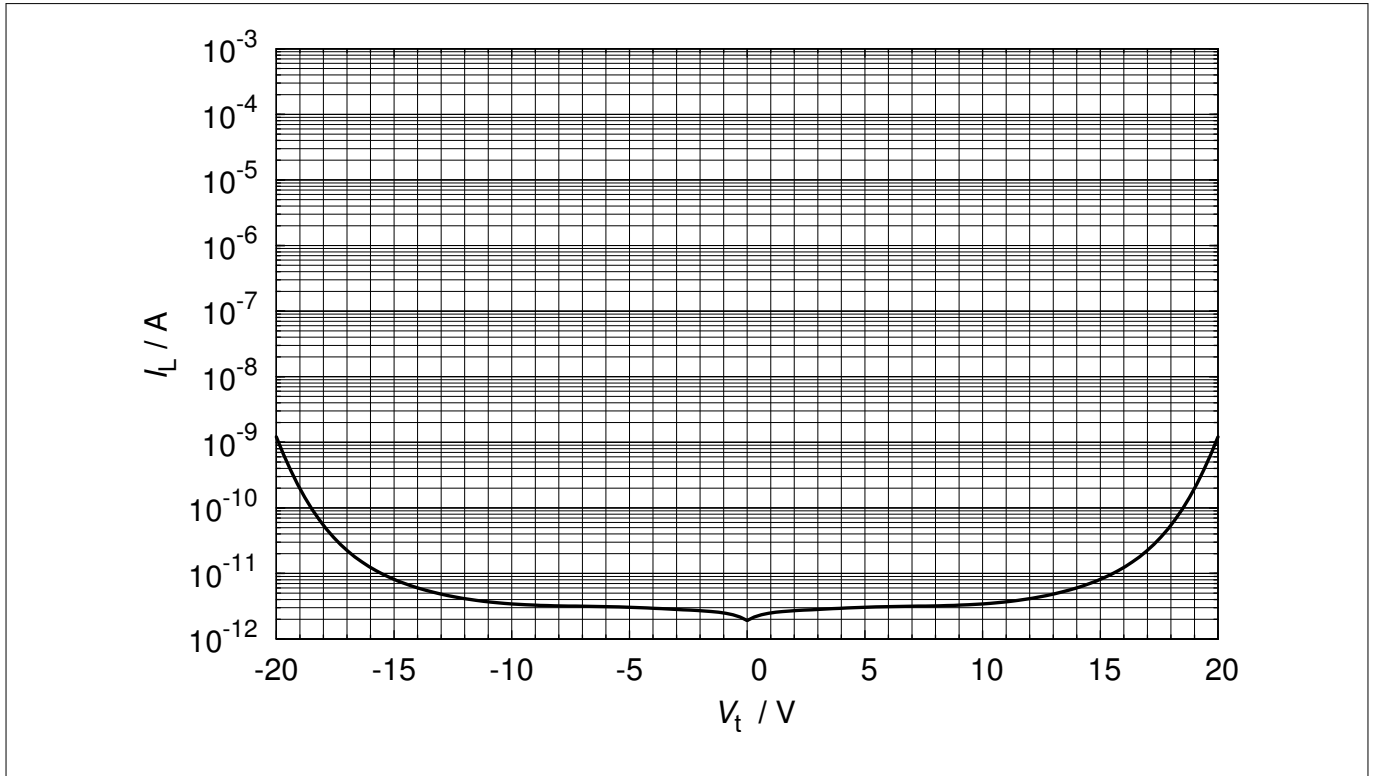
<sup>3)</sup> TLP parameters:  $Z_0 = 50\ \Omega$ ,  $t_p = 100\text{ ns}$ ,  $t_r = 0.6\text{ ns}$ , averaging window 30-60 ns.

<sup>4)</sup> Refer to application note AN210 [2]

**3 Typical characteristic diagrams**

**3 Typical characteristic diagrams**

Note:  $T_A = 25^\circ\text{C}$ , unless otherwise specified.



**Figure 3** Leakage current  $I_L = f(V_t)$

3 Typical characteristic diagrams

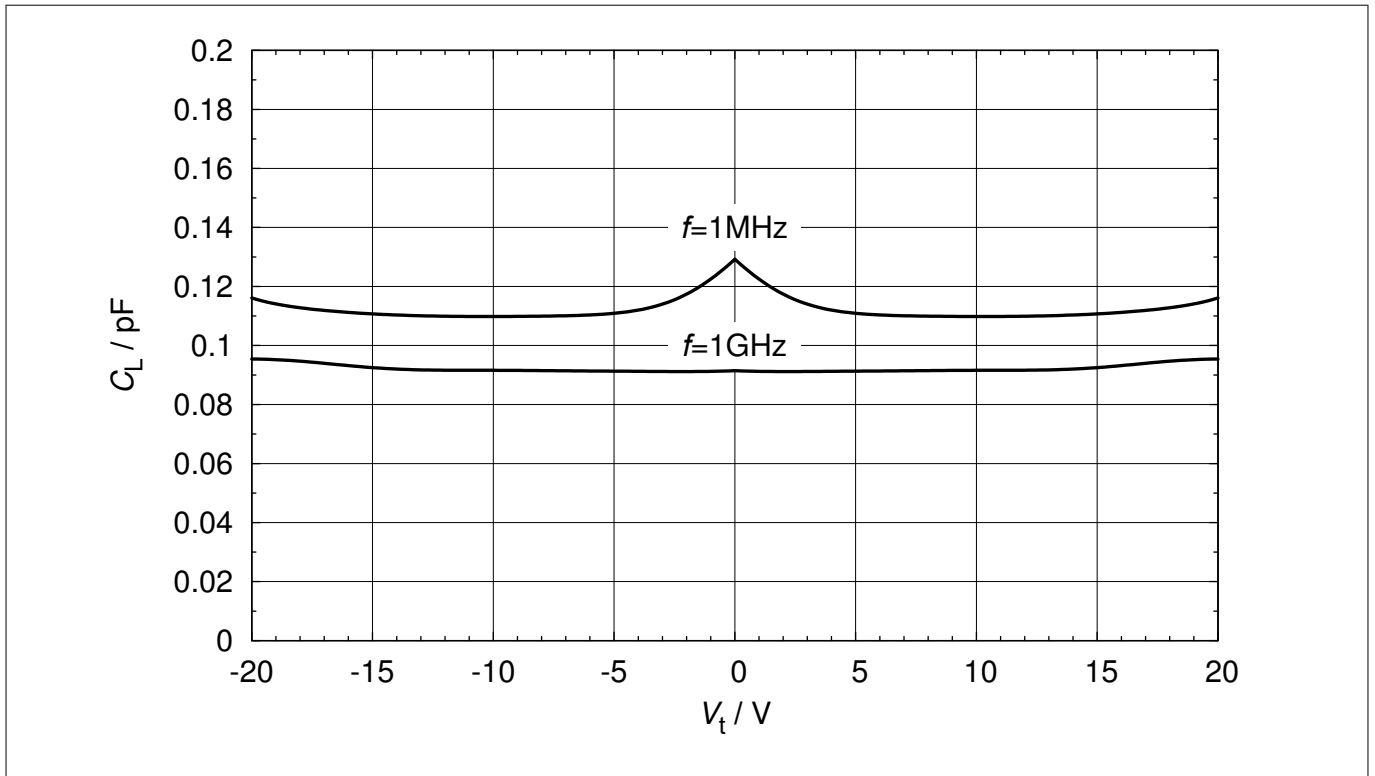


Figure 4 Line capacitance  $C_L = f(V_t)$ ,  $f = 1\text{ MHz}, 1\text{ GHz}$

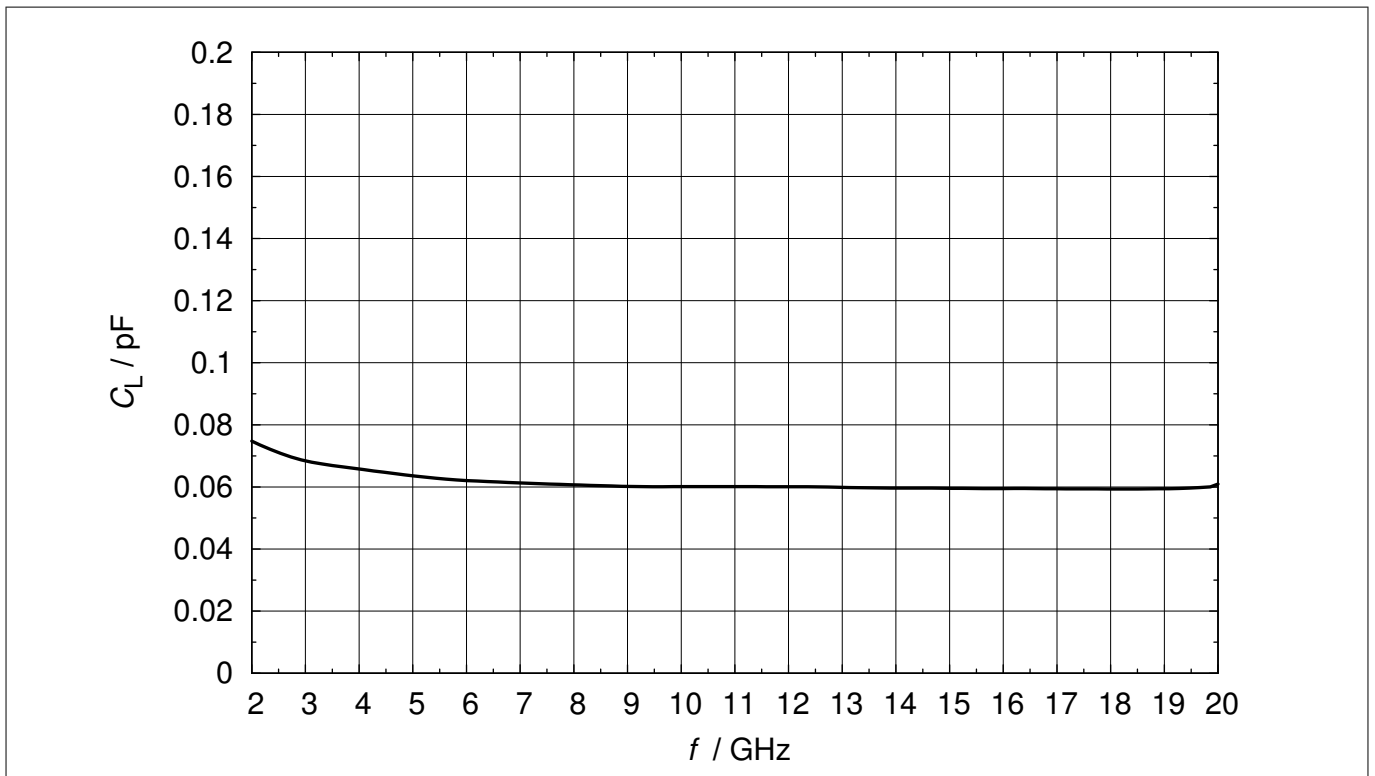


Figure 5 Line capacitance:  $C_L = f(f)$ ,  $V_t = 0\text{ V}$

3 Typical characteristic diagrams

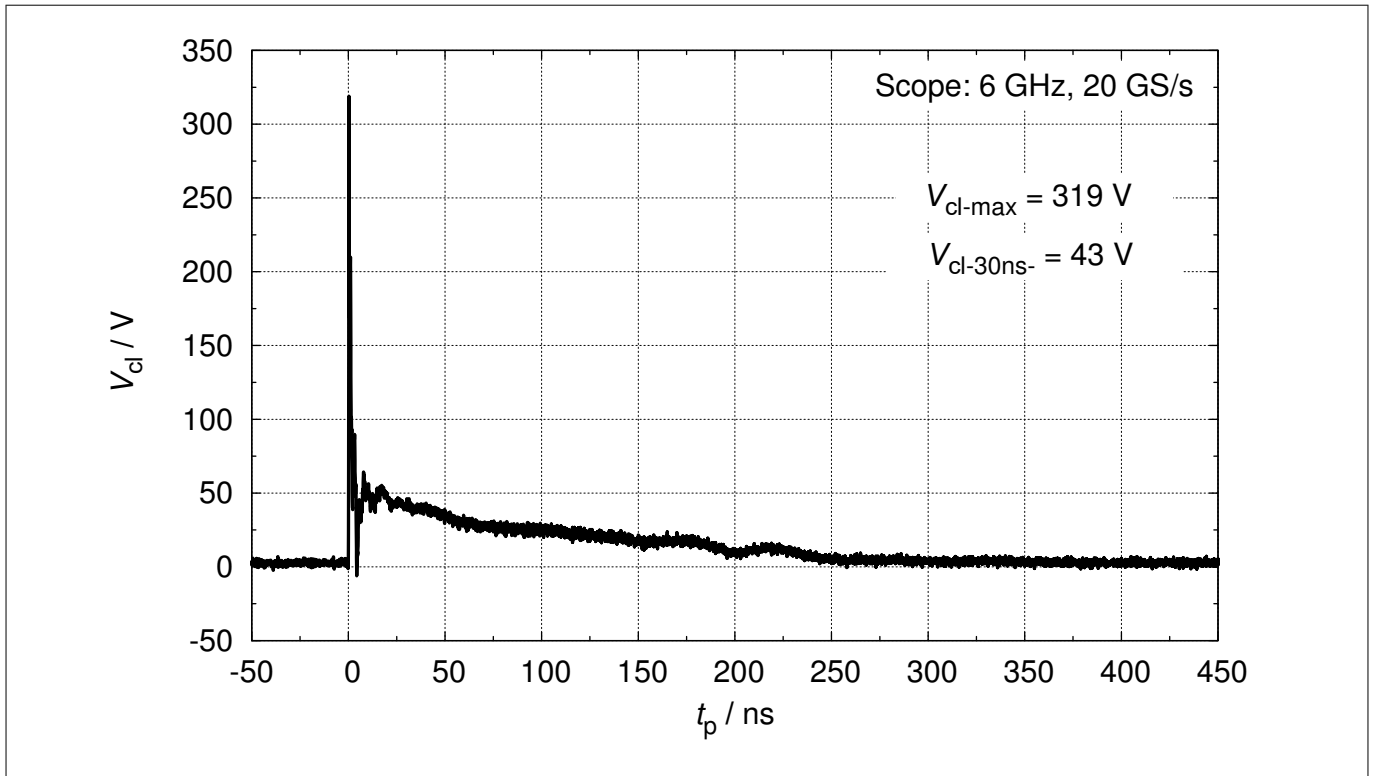


Figure 6 Clamping voltage (ESD):  $V_{cl} = f(t_p)$ , 8 kV positive pulse based on IEC61000-4-2

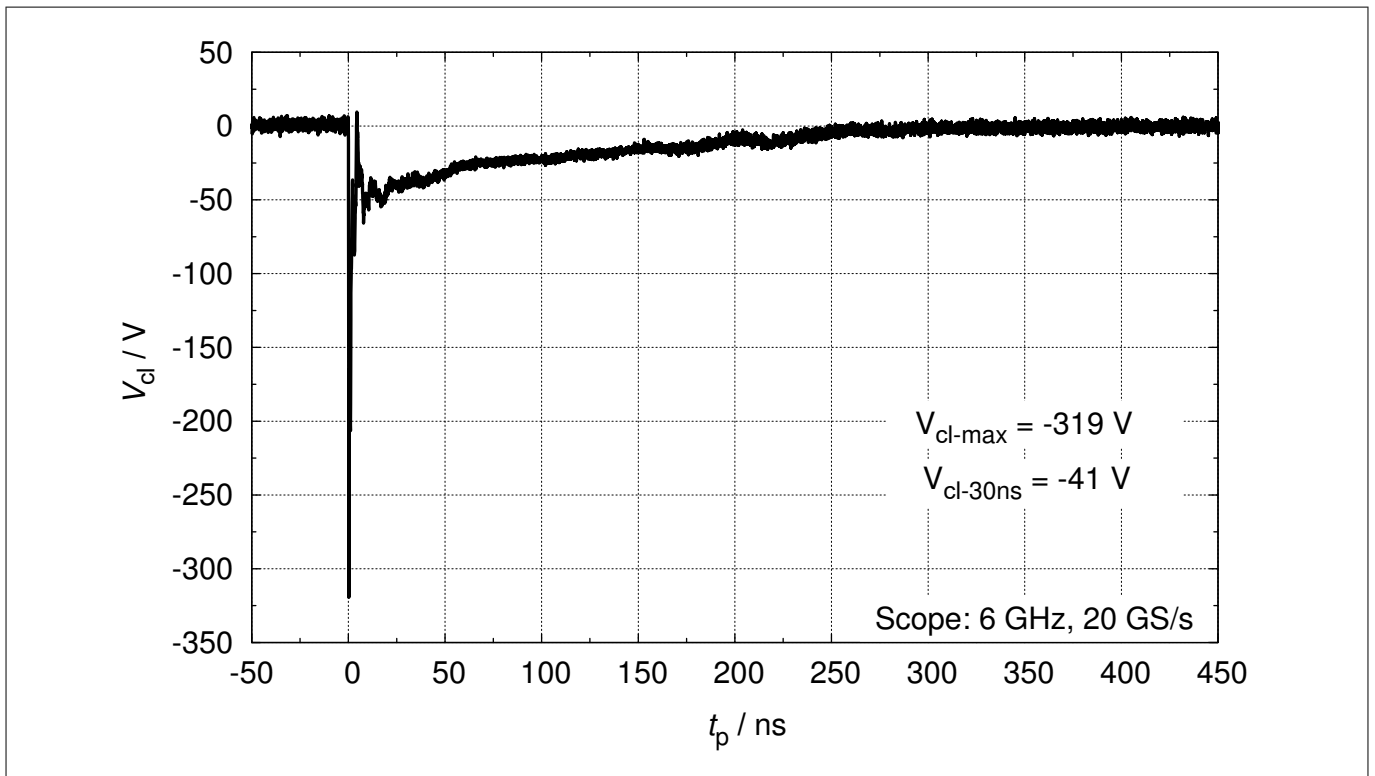


Figure 7 Clamping voltage (ESD):  $V_{cl} = f(t_p)$ , 8 kV negative pulse based on IEC61000-4-2



3 Typical characteristic diagrams

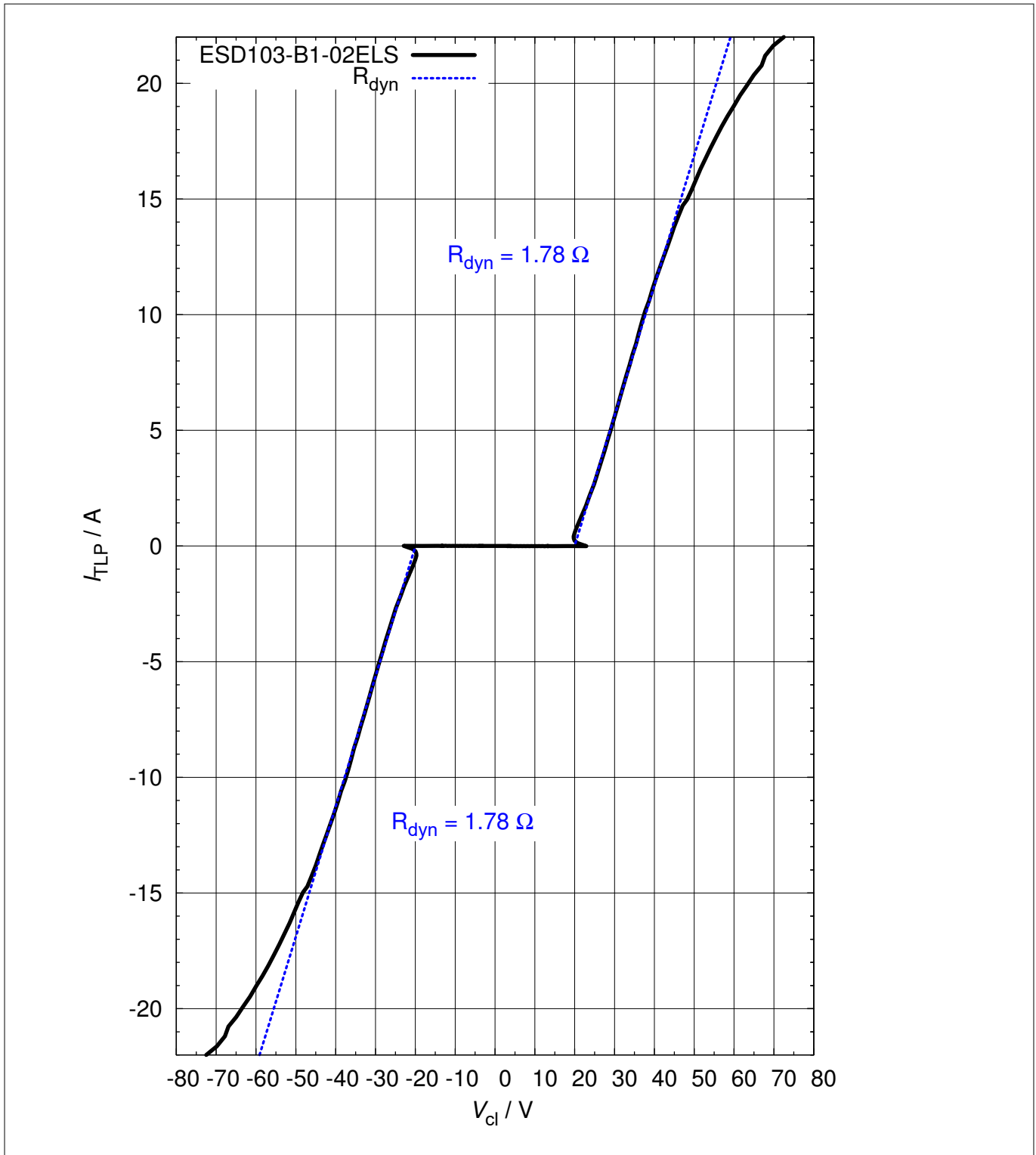


Figure 8 Clamping voltage (TLP):  $I_{TLP} = f(V_{cl})$

4 Package information TSSLP-2-4

4 Package information TSSLP-2-4

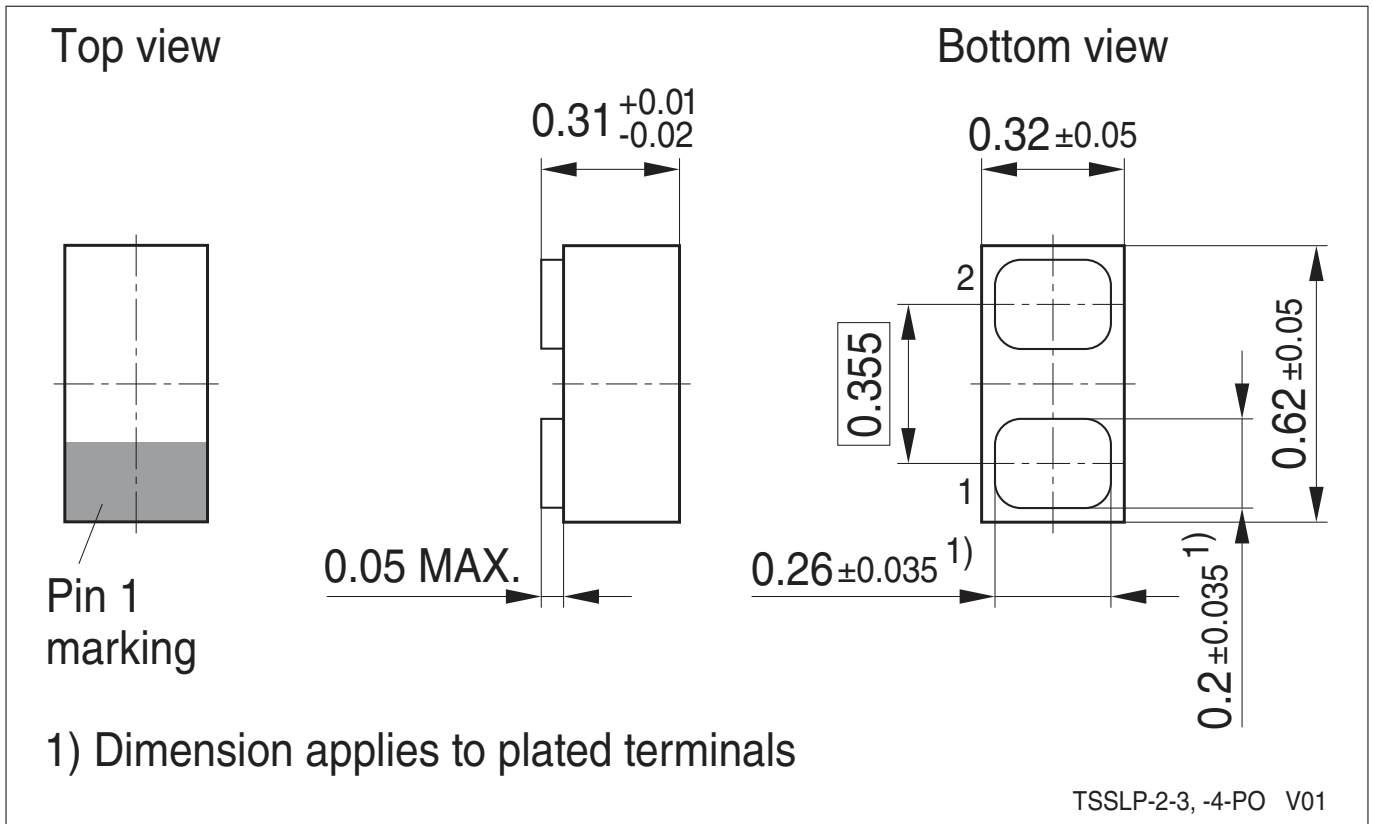


Figure 9 TSSLP-2-4 package

Note: For package information including footprint, packing and assembly recommendation refer to:

<https://www.infineon.com/cms/en/product/packages/PG-TSSLP/PG-TSSLP-2-4/>

**5 References****5 References**

[1]	Infineon AG - Understanding ESD protection device characteristics
[2]	Infineon AG - <b>Application note AN210</b> : Effective ESD Protection Design at System Level Using VF-TLP Characterization Methodology

**6 Revision history**

<b>Document version</b>	<b>Date of release</b>	<b>Description of changes</b>
v1.3	2014-06-12	<ul style="list-style-type: none"><li>• Table 5 updated</li></ul>
v2.0	2023-02-02	<ul style="list-style-type: none"><li>• New datasheet layout</li></ul>

## Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

**Edition 2023-02-02**

**Published by**

**Infineon Technologies AG**

**81726 Munich, Germany**

**© 2023 Infineon Technologies AG**

**All Rights Reserved.**

**Do you have a question about any aspect of this document?**

**Email: [erratum@infineon.com](mailto:erratum@infineon.com)**

**Document reference**

**IFX-ahl1647426227436**

## Important notice

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

## Warnings

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.